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# Tuning the optical properties of monolayer WS<sub>2</sub> for near-infrared-II photothermal therapy: a first-principles study

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Photothermal therapy (PTT) is a new therapeutic cancer treatment strategy that offers many advantages over traditional cancer treatments, such as minimal invasiveness, higher specificity, and precise temporal selectivity. Optical imaging in the second near-infrared region (NIR-II, 1000–1350 nm) has prospective applications in PTT and is superior to that in the first near-infrared region (650–1000 nm). However, it proves challenging to find NIR-II materials. To resolve this, several elements were tested *via* substitutional doping to tune the bandgap of monolayer tungsten disulfide (WS<sub>2</sub>). Two-dimensional materials have long been proved to offer various properties, with WS<sub>2</sub> predicted to have ideal adjustable optical properties. Density functional theory calculations revealed the band structure and optical spectra of the differently doped monolayer WS<sub>2</sub>. The bandgap of monolayer WS<sub>2</sub> was successfully tailored to activate absorption in the NIR-II region. The results show that zirconium doped WS<sub>2</sub> had a bandgap of 0.04 eV and titanium doped WS<sub>2</sub> had a bandgap of 0.06 eV, which was ideal for NIR-II. Doping with zirconium or titanium exhibits strong absorption in the NIR-II range with absorption coefficients of 18 830 and 13 314 cm<sup>-1</sup>, respectively, which is very competitive for PTT. This demonstrates the potential of these materials as NIR-II photothermal agents.

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## 1 Introduction

Pioneering cancer research and treatment have been carried out for decades, yet cancer metastasis stands as one of the most critical challenges in the medical field and is a primary cause of cancer mortality.<sup>1</sup> Currently, one in three women and one in two men in the United States develop cancer in their lifetime; however, a reliable cure is yet to be found for multiple forms of cancer.<sup>2</sup> Metastasis is a complex multi-step process in which cancer cells from a primary tumor colonize distant secondary sites.<sup>3</sup> Treatments for metastasis have been developed since its discovery. One such treatment is surgery, which proves to be ineffective, highly invasive, and causes psychological and physical distress.<sup>4–6</sup> Other treatments, such as chemotherapy,<sup>7</sup> radiotherapy,<sup>8</sup> or immunotherapy,<sup>9</sup> often result in damage to healthy tissues near the targeted tumor or side effects that may permanently change the body.<sup>4,10–12</sup> One treatment offers the promise of a solution to those problems. Photothermal therapy (PTT) is an emerging and prospective therapeutic strategy for targeted cancer treatment that offers many advantages over traditional treatments and has attracted much attention recently.<sup>13</sup>

Photothermal therapy induces cancer cell death through hyperthermia and employs near-infrared (NIR) laser irradiation

to excite photoabsorbers previously dispatched to designated tumor sites.<sup>14</sup> These photoabsorbers are often nanoparticles smaller than 50 nm in width which are inserted into the bloodstream and reach the tumor site through passive or active targeting.<sup>15</sup> The photoabsorbers convert the photonic energy from the NIR radiation into heat, leading to the ablation of the tumor cells.<sup>16</sup> Tumors are destroyed because of their reduced heat tolerance compared to normal tissue due to their poor blood supply.<sup>17</sup> It is common for the intracellular temperature of cancer cells to reach above 50 degrees Celsius, resulting in necrosis and rapid cell death.<sup>18</sup> Photothermal therapy exhibits high specificity, minimal invasiveness, and precise temporal selectivity.<sup>14</sup> This method can be used to suppress and eradicate tumor cells while keeping the nearby tissues largely unaffected. Moreover, photothermal therapy can be combined with other cancer treatments to guarantee and further the effectiveness of metastatic tumor treatment.<sup>19</sup>

Photothermal therapy in the second near-infrared biological window (NIR-II, 1000–1350 nm)<sup>20</sup> shows a significant advantage over that in the first near-infrared biological window (NIR-I, 650–1000 nm)<sup>20</sup> in terms of maximum permissible exposure (MPE), penetration depth, and reduced tissue scattering.<sup>21–23</sup> This allows treatment of tumors that may be larger or deeper inside the body. Despite this, photothermal conversion nanoagents for NIR-II have been rarely developed and reported, making finding new NIR-II materials a crucial and pressing task.<sup>24</sup> To be an

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effective photothermal agent, a nanomaterial must be able to absorb light in the NIR-II region and convert the light energy into heat, otherwise known as photothermal conversion efficiency (PCE).<sup>25,26</sup> The key to improving the photothermal therapy is selecting ideal photosensitive agents that can absorb the ideal radiation wavelength and have enhanced absorption efficiency.<sup>27</sup>

Since the groundbreaking discovery of graphene and the subsequent Nobel prize,<sup>28</sup> novel two-dimensional nanomaterials have gained increasing interest for their potential applications in various fields, including photothermal therapy, because of their distinct electrical and optical properties.<sup>29</sup> 2D materials differ in these properties from their bulk form due to the confinement of electrons but also due to the absence of inter-layer interactions, which, despite being very weak, play an important role in determining the band structure.<sup>30</sup> This allows 2D materials to have clear advantages in bandgap modulation. Transition Metal Dichalcogenides (TMDCs) are a class of 2D materials, similar to graphene, with the formula  $\text{MX}_2$ , where M is a transition metal element (typically from Group IV to Group X) and X is a chalcogen.<sup>31,32</sup> The family has been hypothesized to comprise semiconductors, and a few have already been experimentally found to be such.<sup>31</sup>  $\text{WS}_2$  is a semiconducting material within the family of TMDCs with a tunable bandgap and has been tested in various optical uses and shows promise for being a good photothermal agent.<sup>33,34</sup>  $\text{WS}_2$  possesses high carrier dynamics, high third-order nonlinear susceptibility, and broadband light absorption.<sup>35</sup> Moreover, the theoretical models predict that  $\text{WS}_2$  has the highest carrier mobility among the semiconducting TMDCs due to better ballistic performance.<sup>36</sup> Because of the weak interactions between layers and strong interactions within the layers of bulk  $\text{WS}_2$ , ultra-thin crystals can be achieved *via* efficient exfoliation.<sup>37</sup> This monolayer  $\text{WS}_2$  has a direct bandgap with extraordinary optical properties and different properties from its bulk form.<sup>38,39</sup> Despite the promising properties, there have been fewer theoretical studies on  $\text{WS}_2$  compared to its counterpart TMDC materials. In this study, we theoretically study the electronic structure and optical properties of monolayer  $\text{WS}_2$ . Doping is implemented to tune the electronic and optical properties of  $\text{WS}_2$  for NIR-II photothermal therapy and has been previously used for changing the optical properties of other materials used in photothermal therapy.<sup>40–42</sup> Through testing of different dopant agents, we successfully tailored the bandgap structure of monolayer  $\text{WS}_2$  and activated its absorption in the NIR-II region.

Our first-principles calculations, based on the density functional theory (DFT) method, are discussed in Section 2, while the results of this study are reported and discussed in Section 3. Finally, Section 4 includes an analysis of the impact of these findings, along with a concluding statement.

## 2 Methods

### 2.1 Computational details

We performed first-principles calculations based on Density Functional Theory (DFT) using the Generalized Gradient

**Table 1** Electron structure and radial cutoff for elements used in this study to generate PAW pseudopotentials

Element	Electron structure	Radial cutoff (bohr)
W	[Kr 4d <sup>10</sup> 4f <sup>14</sup> ] 5s <sup>2</sup> 5p <sup>6</sup> 6s <sup>2</sup> 5d <sup>4</sup>	2.41
S	[Ne] 3s <sup>2</sup> 3p <sup>4</sup>	1.92
C	[He] 2s <sup>2</sup> 2p <sup>2</sup>	1.51
N	[He] 2s <sup>2</sup> 2p <sup>3</sup>	1.20
O	[He] 2s <sup>2</sup> 2p <sup>4</sup>	1.42
F	[He] 2s <sup>2</sup> 2p <sup>5</sup>	1.41
Si	[Ne] 3s <sup>2</sup> 3p <sup>2</sup>	1.91
P	[Ne] 3s <sup>2</sup> 3p <sup>3</sup>	1.91
Sc	[Ne] 3s <sup>2</sup> 3p <sup>6</sup> 4s <sup>2</sup> 3d <sup>1</sup>	2.43
Ti	[Ne] 3s <sup>2</sup> 3p <sup>6</sup> 4s <sup>1</sup> 3d <sup>3</sup>	2.30
V	[Ne] 3s <sup>2</sup> 3p <sup>6</sup> 4s <sup>2</sup> 3d <sup>3</sup>	2.20
Mn	[Ne] 3s <sup>2</sup> 3p <sup>6</sup> 4s <sup>1</sup> 3d <sup>6</sup>	2.18
Se	[Ar 3d <sup>10</sup> ] 4s <sup>2</sup> 4p <sup>4</sup>	2.20
Zr	[Ar 3d <sup>10</sup> ] 4s <sup>2</sup> 4p <sup>6</sup> 5s <sup>1</sup> 4d <sup>3</sup>	2.21
Nb	[Ar 3d <sup>10</sup> ] 4s <sup>2</sup> 4p <sup>6</sup> 5s <sup>1</sup> 4d <sup>4</sup>	2.21
Mo	[Ar 3d <sup>10</sup> ] 4s <sup>2</sup> 4p <sup>6</sup> 5s <sup>1</sup> 4d <sup>5</sup>	2.20
Au	[Xe 4f <sup>14</sup> ] 6s <sup>1</sup> 5d <sup>10</sup>	2.50

Approximation (GGA) exchange-correlation in the Perdew–Burke–Ernzerhof (PBE)<sup>43</sup> format implemented in the ABINIT<sup>44,45</sup> code. We use the Projected Augmented Wave (PAW) pseudopotentials<sup>46</sup> with projectors generated using the ATOM-PAW code.<sup>47,48</sup> The electronic structure and radius cutoff of the PAW pseudopotentials are shown in Table 1.

In total energy calculations, self-consistent cycles were recognised when the total energy difference was less than  $1.0 \times 10^{-10}$  Hartree twice consecutively. The kinetic energy cutoff, the density of the Monkhorst–Pack grid, and vacuum height of the unit cell were converged until the difference between successive datasets reached a tolerance criterion of  $1.0 \times 10^{-4}$  Hartree, which equates to nearly 2.72 meV.

The Broyden–Fletcher–Goldfarb–Shanno (BFGS) minimization algorithm was used to perform structural optimization. The atomic structure was relaxed until the maximum atomic forces were less than  $5.0 \times 10^{-5}$  Hartree bohr<sup>-1</sup>.

A  $2 \times 2$  supercell is used to calculate the doped  $\text{WS}_2$  materials. In these calculations, the kinetic energy cutoff is once again chosen to be converged until the difference between successive datasets reaches a tolerance criterion of  $1.0 \times 10^{-4}$  Hartree. The *k*-point mesh was divided by two along the lateral directions as the lattice constant was doubled and the vacuum height was reconverged. The lattice optimization was then calculated. This was applied to every dopant system.

### 2.2 Atomic structure

Monolayer transition metal dichalcogenides exist in different structural polytypes. TMDCs can exist in a semiconducting trigonal prismatic phase (1H) and a metallic octahedral prismatic phase (1T). A third, deformed version of the 1T phase can also be observed (1T'). The 1H form is the primary focus of this study<sup>49</sup> since it is the most stable form as discussed later. Monolayer  $\text{WS}_2$  is composed of one layer of tungsten atoms in between two layers of sulfur atoms. The atoms of different layers are bonded with strong covalent bonds. The atomic structure of pristine 1H- $\text{WS}_2$  can be seen in Fig. 1.

2D TMDCs have previously been doped by substitutional doping at the M (metal, W) and X (chalcogen, S) sites. It was



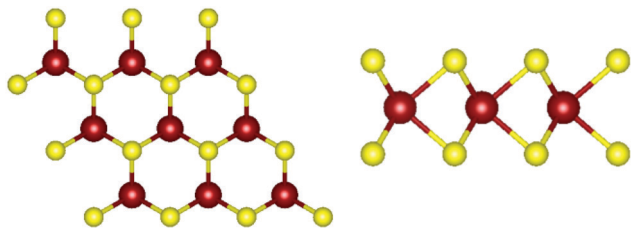


Fig. 1 Atomic structure of WS<sub>2</sub>. (left) Top view of monolayer WS<sub>2</sub>. (right) Side view of monolayer WS<sub>2</sub>. Tungsten atoms are depicted in red and sulfur atoms are depicted in yellow.

found that doping concentrations greater than 1% were needed for changes in the electronic structure.<sup>50</sup> For M site substitution, one of the four tungsten atoms was replaced, giving a 25% concentration. For X site substitution, one of the eight sulfur atoms were replaced, giving a 12.5% concentration.<sup>50,51</sup> This can be seen in Fig. 2.

Neighboring elements are chosen to replace either the tungsten or the sulfur atom. Elements used as dopants and tested in this study are shown in Fig. 3 in a periodic table.

### 2.3 Formation energy

The total energy of the crystalline structure was calculated both with and without the dopant atom. The formation energy can then be obtained from the following equation

$$E_{\text{formation}} = E_{\text{WS}_2+\text{DP}} - E_{\text{WS}_2} - E_{\text{DP}} + E_{\text{SB}} \quad (1)$$

where  $E_{\text{WS}_2}$  is the total energy of the pristine complex,  $E_{\text{DP}}$  is the total energy of the dopant atom in their stable structure,  $E_{\text{SB}}$  is the total energy of the atom being substituted by the dopant in their stable structure, and  $E_{\text{WS}_2+\text{DP}}$  is the total energy of the doped complex. The magnitudes of the formation energies give insight into the thermodynamic stability of the doped structures.

### 2.4 Electronic structure

The 3D Bravais lattice is expressed by its primitive vectors ( $a_1$ ,  $a_2$ ,  $a_3$ ) through the following real space translational vector:

$$\vec{R}_n = n_1\vec{a}_1 + n_2\vec{a}_2 + n_3\vec{a}_3 \quad \text{where } n_1, n_2, n_3 \in Z \quad (2)$$

The corresponding reciprocal space translational vector can be expressed using

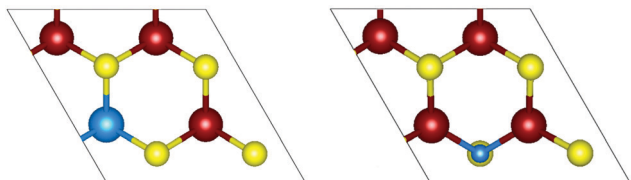


Fig. 2 Top view of monolayer WS<sub>2</sub> doping. (left) Tungsten substitution, M site doping, with dopant in the 2 × 2 supercell. (right) Sulfur substitution, X site doping, with dopant in the 2 × 2 supercell. Tungsten atoms are depicted in red, sulfur atoms are depicted in yellow, and the substituting dopant atom is depicted in blue.

1	H																	2	He						
3	Li	Be																	10	B	C	N	O	F	Ne
11	Na	Mg																	13	Al	Si	P	S	Cl	Ar
19	K	Ca	Sc	Ti	V	Cr	Mn	Fe	Co	Ni	Cu	Zn	Ga	Ge	As	Se	Br	Kr							
37	Rb	Sr	Y	Zr	Nb	Mo	Tc	Ru	Rh	Pd	Ag	Cd	In	Sn	Sb	Te	I	Xe							
87	Cs	Ba	Hf	Ta	W	Re	Os	Ir	Pt	Au	Hg	Tl	Pb	Bi	Po	At	Rn								

Fig. 3 Periodic table of elements used in doping. All elements tested in this study are shown. Elements used with M site doping are colored in red, elements used with X site doping are colored in yellow.

$$\vec{G}_m = m_1\vec{b}_1 + m_2\vec{b}_2 + m_3\vec{b}_3 \quad (3)$$

and

$$\begin{aligned} \vec{b}_1 &= 2\pi \frac{\vec{a}_2 \times \vec{a}_3}{\vec{a}_1 \cdot (\vec{a}_2 \times \vec{a}_3)} \\ \vec{b}_2 &= 2\pi \frac{\vec{a}_1 \times \vec{a}_3}{\vec{a}_2 \cdot (\vec{a}_1 \times \vec{a}_3)} \\ \vec{b}_3 &= 2\pi \frac{\vec{a}_1 \times \vec{a}_2}{\vec{a}_3 \cdot (\vec{a}_1 \times \vec{a}_2)} \end{aligned} \quad (4)$$

The orbital projected band structures for WS<sub>2</sub> and its dopant variants are calculated. A high symmetry  $k$ -point circuit  $\Gamma(0,0,0)$ ,  $M\left(\frac{1}{2}, 0, 0\right)$ ,  $K\left(\frac{1}{3}, \frac{1}{3}, 0\right)$ ,  $\Gamma(0,0,0)$  was used to sample the irreducible first Brillouin zone (IBZ) as shown in Fig. 4. We also plot the projected density of states, which show the orbital decomposition of density of states for each atom.

The band structures and projected density of states (PDOS) of pristine WS<sub>2</sub> are shown in Fig. 5. It should be noted that the theoretical GGA-PBE calculations may deviate from the experimental bandgap. The Fermi level is set to 0. It shows that pristine WS<sub>2</sub> is a clear direct semiconductor with a direct bandgap of 1.81 eV at the  $K$  symmetry point. The tungsten d-orbitals contribute the most to all bands. The eigenvalues at the  $\Gamma$  symmetry point are comparable in value to those at the  $K$

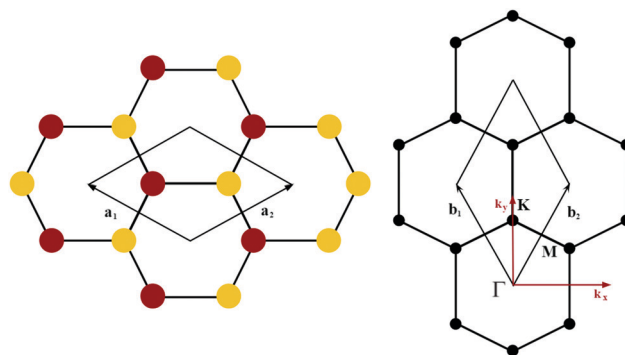


Fig. 4  $K$ -point circuit. (left) Real space vectors of WS<sub>2</sub>. Tungsten atoms are depicted in red and sulfur atoms are depicted in yellow. (right) The reciprocal space of WS<sub>2</sub>. The  $k$ -point circuit was formed with  $\Gamma(0,0,0)$ ,  $M\left(\frac{1}{2}, 0, 0\right)$ ,  $K\left(\frac{1}{3}, \frac{1}{3}, 0\right)$ ,  $\Gamma(0,0,0)$ .



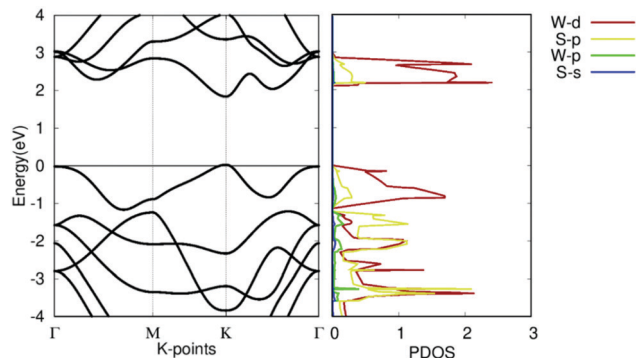


Fig. 5 Electronic structure of pristine WS<sub>2</sub>. (left) Band structure of pristine WS<sub>2</sub>. (right) Projected density of states of pristine WS<sub>2</sub>.

symmetry point, showing the potential that WS<sub>2</sub> may become a *K*- $\Gamma$  indirect semiconductor with defect changes. This bandgap and band structure agrees with other research, which reinforces our calculation methodology and verifies our work with previous calculations.<sup>37,52</sup>

## 2.5 Optical calculations

The photonic energy of light can be calculated by the following equation:

$$E = \frac{hc}{\lambda} \quad (5)$$

where  $h$  is Planck's constant,  $c$  is the speed of light in a vacuum, and  $\lambda$  is the wavelength. This yields an energy range of about 0.92–1.24 eV for NIR-II (1000–1350 nm). The absorption coefficient  $\alpha(E)$  for a semiconductor for transmissions is generalized to behave like<sup>53</sup>

$$\alpha(E < E_{\text{gap}}) = 0 \quad (6)$$

and

$$\alpha(E \geq E_{\text{gap}}) \propto \sqrt{(E - E_{\text{gap}})} \quad (7)$$

This means that as long as the photonic energy is greater than the bandgap of a semiconductor, it may be absorbed. Thus, for NIR-II light to be absorbed, the bandgap for potential photothermal agents must have a bandgap less than the photonic energy of the NIR-II light. As a result  $E_g \leq (0.92\text{--}1.24 \text{ eV}) \rightarrow E_g \leq 0.92 \text{ eV}$ .

Dopants that met the bandgap requirement had their optical spectra calculated. For this, the Kohn–Sham band structure is further corrected using GW quasiparticle calculations to determine a corrected bandgap. Bethe–Salpeter equations (BSE) from the ABINIT software are used to calculate the macroscopic dielectric constants, using a scissor operator which shifts both conduction bands. Using the Many-Body Perturbation Theory (MBPT), Bethe–Salpeter equations take into account electron–hole interactions and provide a much more accurate calculation, especially in the low energy ranges.<sup>54</sup> A standard excitonic calculation within the Tamm–Dancoff approximation (TDA) using the Haydock iterative technique was used. The calculation included local-field effects and used an automatically calculated Coulomb term evaluated using truly non-local screening  $W(r, r')$ .

The macroscopic dielectric function,  $\epsilon_M^{\text{LF}}(\omega)$ , is directly related to the inverse of the first element of the inverse of the microscopic dielectric matrix by means of

$$\epsilon_M^{\text{LF}}(\omega) = \lim_{q \rightarrow 0} \frac{1}{\epsilon_{00}^{-1}(q, \omega)} \quad (8)$$

The optical absorption spectrum is simply given by the imaginary part of  $\epsilon_M^{\text{LF}}(\omega)$ . The imaginary part is called  $\epsilon_2$ . Note that this equation takes into account local fields, which makes it more accurate.

The imaginary dielectric constant is calculated with the equation:

$$\epsilon_2(\omega) = \frac{2e^2\pi}{\Omega\epsilon_0} \sum_{k,v,c} |\langle \psi_k^c | s\hat{u} \cdot r | \psi_k^v \rangle|^2 \delta(E_k^c - E_k^v - \hbar\omega) \quad (9)$$

where  $\omega$  is the light frequency, and  $\psi_k^c$  and  $\psi_k^v$  are, respectively, the conduction band and valence band wave functions at  $k$  calculated using the GGA approach. The vector  $\hat{u}$  points along the polarization of the effective electric field.

The iterative Haydock technique was stopped when the difference between two consecutive evaluations of the optical spectra became less than 0.05 eV. The screening was formatted with an unsymmetrical  $k$ -mesh (shifted along the primitive axis by 0.11, 0.21, and 0.31). The imaginary dielectric constant was plotted against light intensities from 0 to 3 eV at intervals of 0.02 eV. The absorption coefficient is plotted against wavelengths ranging from 700 to 1700 nm. Both the real and imaginary dielectric constants,  $\epsilon_1$  and  $\epsilon_2$  were calculated. They are related to the refractive index  $n$  and extinction coefficient  $\kappa$  through the equations

$$\epsilon_1 = n^2 - \kappa^2 \quad (10)$$

$$\epsilon_2 = 2n\kappa \quad (11)$$

The absorption coefficient can then be calculated with respect to  $\kappa$ :

$$\alpha = \frac{4\pi\kappa}{\lambda} \quad (12)$$

The optical properties of WS<sub>2</sub> are shown in Fig. 6. Due to the high bandgap of pristine WS<sub>2</sub>, it has very low absorption in ranges below its bandgap. It shows a minor peak at 2.5 eV in the imaginary part of the complex dielectric function. It appears to have no peak in the absorption spectrum, with the maxima being below 700 nm. These results appear to be similar to other studies.<sup>55</sup> This shows that pristine WS<sub>2</sub> is clearly not ideal for NIR-II applications. Thus, it is necessary to engineer the optical properties of WS<sub>2</sub>.

## 3 Results and discussion

### 3.1 Atomic structure and doping

WS<sub>2</sub> in its monolayer trigonal prismatic (1H) form was tested. The crystal was in a hexagonal structure with the space group  $P6(3)/mmc$ .<sup>37</sup> While WS<sub>2</sub> technically exists in the 1H, 1T, and 1T' phases, there is still controversy regarding the electronic properties of the 1T and 1T' phases.<sup>56</sup> Because WS<sub>2</sub> is a group VI





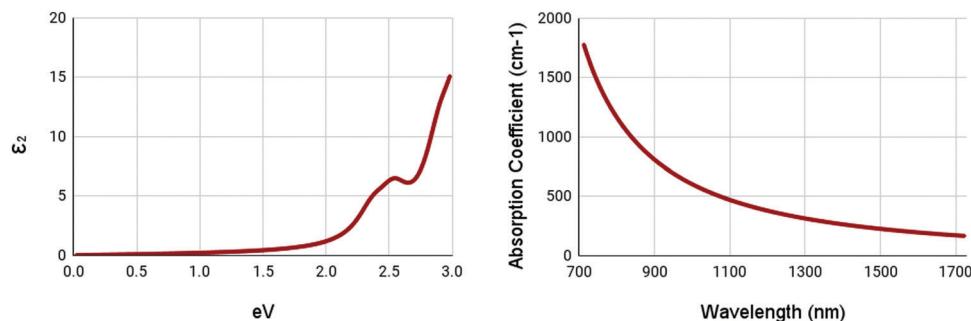


Fig. 6 Optical spectra of pristine WS<sub>2</sub>. (left) Imaginary dielectric constant,  $\epsilon_2$  of pristine WS<sub>2</sub>. (right) Absorption coefficient of pristine WS<sub>2</sub>.

TMDC, it is more likely to exist in the 1H or 2H phase.<sup>57</sup> This is because the ground state energy of the 1T phase is 85 meV higher than that of the 1H phase. This means that the 1T phase is metastable and will turn into the 1H phase spontaneously under normal conditions.<sup>56</sup> While it is possible to create 1T WS<sub>2</sub> with processes such as heating and annealing treatments,<sup>58</sup> lithium intercalation, and electron beam stimulation,<sup>57</sup> it has never been observed in natural crystals.<sup>58</sup>

The intrinsic doping behaviors of TMDCs are believed to spawn from defect formation during the fabrication process. Unfortunately, these defects are difficult to control, with reports of Fermi levels varying by up to 1 eV between regions separated by only tens of nanometers.<sup>59</sup> Thus, efforts have been made to develop methods to reliably dope TMDCs. One promising approach is the substitutional doping of the transition metal atom, in this case, tungsten. For a given TMDC, both the conduction band minimum (CBM) and valence band maximum (VBM) belong to d-orbitals on the transition metal.<sup>60</sup> This means that substituting with a transition metal atom possessing one more/fewer valence electron will induce n/p-type doping. If the atomic radius of the dopant is similar to that of the host, a minor strain will be put on the crystal structure, maintaining a clean and stable surface.<sup>51</sup> Substitutional doping of the sulfur atom has also been tested for WS<sub>2</sub>, creating bond changes and altering the bandgap.<sup>61</sup>

With a  $2 \times 2$  supercell, substitutional doping was carried out. As mentioned before, the crystal structures were atomically relaxed to ideal positions. Table 2 lists the structural parameters of M site dopants on top and the X site dopants on the bottom after being relaxed.

To evaluate the thermodynamic stability of these structures, the calculation of the formation energies was carried out as from eqn (1). Table 3 lists the formation energies for all doped structures. With the exception of Si, Mn, Mo, Au, and F doping, all structures were found to have negative formation energies, showing that those materials were mechanically stable in a natural environment. The doped structures that were found to have positive formation energies are mostly of very small magnitudes.

### 3.2 Electronic structure

Substitutional doping is the most commonly used method for doping TMDCs. While other methods such as introducing surface adatoms or vacancies exist, they are more likely to cause structural and undesirable results. The substitution of the tungsten atom with Si, Sc, Ti, V, Mn, Zr, Nb, Mo, and Au was carried out at a concentration of 25%. The band structures of the different doped variations are shown in Fig. 7.

Organizing the dopants by atomic order, the first dopant is silicon. Fig. 7(a) depicts the band structure and projected density of states for Si-doped WS<sub>2</sub>. It appears to show degenerate doping as the appearance of many band crossings is found near the Fermi level. An unsuccessful bonding between the Si atom and surrounding sulfur atoms was also observed, furthering this argument. The S-3p orbital appears to dominate the states near the Fermi level, as seen in the projected density

Table 2 WS<sub>2</sub> dopant parameters. The bond length,  $a$  lattice parameter, and  $c$  lattice parameter, for all dopants are listed in bohr

Material	M-S bond length			Material	M-S bond length		
	$a$	$c$			$a$	$c$	
Si	4.4711	12.2718	22.3860	Zr	4.7812	12.4906	23.8208
Sc	4.7712	12.4923	21.7523	Nb	4.6524	12.2215	22.2817
Ti	4.5867	12.2427	22.3328	Mo	4.5721	12.0531	20.9875
V	4.8830	12.0653	22.0092	Au	4.8465	12.4760	22.7585
Mn	4.3822	12.0145	22.9128				

Material	X-W bond length			Material	X-W bond length		
	$a$	$c$			$a$	$c$	
C	3.8437	12.0647	21.0078	F	4.3797	11.9285	19.7816
N	3.8112	11.9616	20.8283	P	4.622	12.1136	21.0929
O	3.9412	11.8640	20.6583	Se	4.8158	12.1111	20.0843

Table 3 WS<sub>2</sub> dopant formation energies

Material	Formation energy (eV)	Material	Formation energy (eV)
Si	0.2912	C	-1.5402
Sc	-3.7293	N	-2.4626
Ti	-2.1470	O	-0.5442
V	-0.4327	F	1.5062
Mn	0.5823	P	-1.4313
Zr	-2.4998	Se	-1.7742
Nb	-2.5307		
Mo	0.1048		
Au	0.9433		



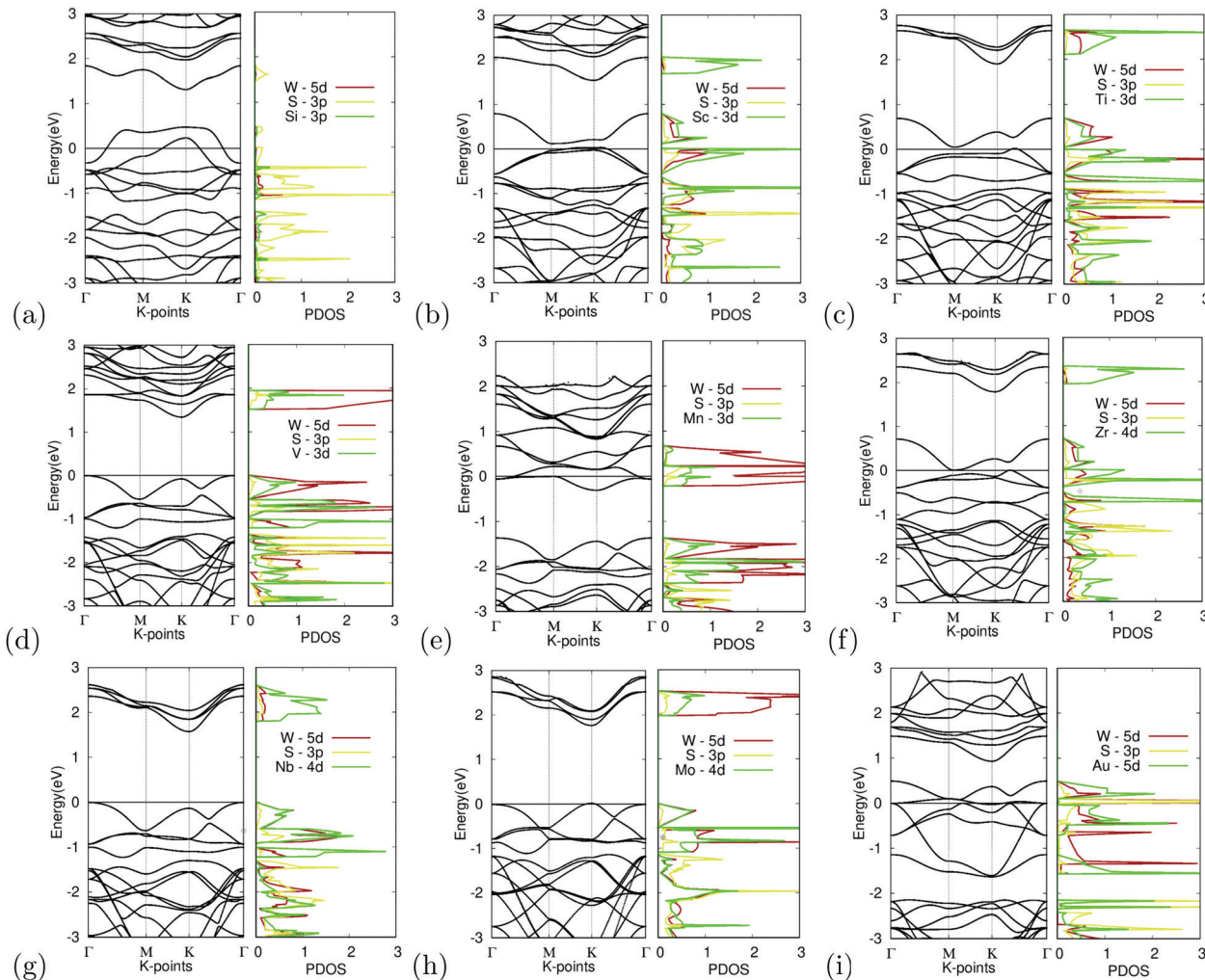


Fig. 7 Electronic structure of M site dopants. (left) Band structure of M site dopants. (right) Projected density of states of M site dopants.

of states. These failures could be caused by the difference in the atomic radii of tungsten and the Si atom, which would cause instability within the crystal.

While doping with silicon had undesirable results, doping with scandium provided the other extreme with large changes in the electronic structure. Fig. 7(b) depicts the band structure and projected density of states for Sc-doped  $\text{WS}_2$ . Doping reduced the bandgap to 0.10 eV. There appears to be a less prominent defect band, with the lowest unoccupied band being closer to the occupied bands than the other unoccupied bands. Since Sc has a 3+ charge, the formation of a donor-level mid-gap band appears. The Sc-3d orbital contributes the most to the CBM. The mid-gap band seems to be equally dominated by the W-5d, S-3p, and Sc-3d orbitals, showing that possible interactions between the Sc and W, S atoms are the cause for the bandgap reduction. Because the bandgap was reduced to less than 0.92 eV, it was suitable for further calculations as shown later.

Similarly, doping with titanium showed similar results to scandium. Fig. 7(c) depicts the band structure and projected density of states for Ti-doped  $\text{WS}_2$ . Doping reduced the

bandgap to near metallic levels with a bandgap of 0.06 eV. It should be noted that there appears to be a defect band, with the lowest unoccupied band being closer to the occupied bands than the other unoccupied bands. Ti is a p-type dopant since tungsten has a 6+ charge while Ti has a 4+ charge. Because of this, the formation of a donor-level mid-gap band appears. The Ti-3d orbital contributes the most to the CBM. The mid-gap band seems to be equally dominated by the W-5d, S-3p, and Ti-3d orbitals, showing that possible interactions between the Ti and W, and S atoms are the cause for the bandgap reduction. Doping with Ti also met the bandgap threshold.

In contrast, doping with vanadium shows an example of successful doping but with relatively small changes to the electronic structure. Fig. 7(d) depicts the band structure and projected density of states for V-doped  $\text{WS}_2$ . Doping with V appeared to result in noticeable changes in the bandgap, which narrowed down to 1.35 eV. The bandgap shifted into a  $K$ - $\Gamma$  indirect bandgap as was predicted to possibly occur earlier. The W-5d orbital contributed the most to the VBM and CBM.

Doping with manganese once again shows an example of incomplete doping. Fig. 7(e) depicts the band structure and



projected density of states for Mn-doped WS<sub>2</sub>. Doping with Mn appears to result in drastic changes in the bandgap, causing the material to become a semi-metal with the formation of a donor-level point at the  $\Gamma$  symmetry point, 0.06 meV below the Fermi level. It was found that the W-5d orbital dominated the contribution of the states around the Dirac point.

Doping with zirconium showed promising results, with attributes similar to that of doping with titanium or scandium. Fig. 7(f) depicts the band structure and projected density of states for Zr-doped WS<sub>2</sub>. Doping reduced the bandgap to near metallic levels with a bandgap of 0.03 eV. It should be noted that there appears to be a defect band, with the lowest unoccupied band being closer to the occupied bands than the other unoccupied bands. Zr is a p-type dopant since tungsten has a 6+ charge while Zr has a 4+ charge. Because of this, the formation of a donor-level mid gap band appears. The Zr-4d orbital contributes the most to the CBM. The mid-gap band seems to be equally dominated by the W-5d, S-3p, and Zr-4d orbitals, showing that possible interactions between the Zr and W, S atoms are the cause for the bandgap reduction. Doping with Zr met the bandgap threshold. It should be noted that Sc, Ti, and Zr, all reduced the bandgap significantly and had mid gap donor states, caused by their p-type doping. Given that these materials were all group III or IV, this may be a trend that continues with the rest of the groups.

Doping with niobium showed successful yet small changes to the electronic structure. Fig. 7(g) depicts the band structure and projected density of states for Nb-doped WS<sub>2</sub>. Doping with Nb appeared only to lead to minor changes in the bandgap, narrowed by 0.10 eV to a bandgap of 1.71 eV. The doping featured no major anomalies except that the bandgap was

shifted into a  $K$ - $\Gamma$  indirect bandgap. The Nb-4d orbital contributes largely to the CBM and VBM, giving reason to believe that the Nb doping was the cause for the bandgap change.

Additionally, doping with molybdenum also had successful yet small changes. Fig. 7(h) depicts the band structure and projected density of states for Mo-doped WS<sub>2</sub>. Doping with Mo appeared only to lead to minor changes in the bandgap, narrowed by 0.07 eV to a bandgap of 1.74 eV. The doping featured no major anomalies. The CBM is primarily dominated by the W-5d orbital while the VBM appears to be equally dominated by the W-5d, S-3p, and Mo-4d orbitals.

Finally, Fig. 7(i) depicts the band structure and projected density of states for Au-doped WS<sub>2</sub>. It appears to show degenerate doping. The appearance of many band crossings is found near the Fermi level. There appears to be a defect bandgap at the  $K$  symmetry point right above the CBM. Besides this, doping with Au appears to be largely unsuccessful. The PDOS shows that the Au-5d and S-3p orbitals seem to dominate the CBM, which gives reason to believe doping with Au to be the cause of this failure.

Out of all the materials tested for M site doping, Sc, Ti, and Zr dopants fitted the bandgap threshold being less than 0.92 eV. V, Nb, and Mo doping all had successful yet minor bandgap changes. Si, Mn, and Au doping resulted in degenerate doping.

The substitution of the sulfur atom with C, N, O, F, P, and Se was also carried out. The band structures of the different doped variations are shown in Fig. 8. Note that X site substitutional doping was carried out at a concentration of 12.5%.

Starting with doping with carbon, Fig. 8(a) depicts the band structure and projected density of states for C-doped WS<sub>2</sub>.

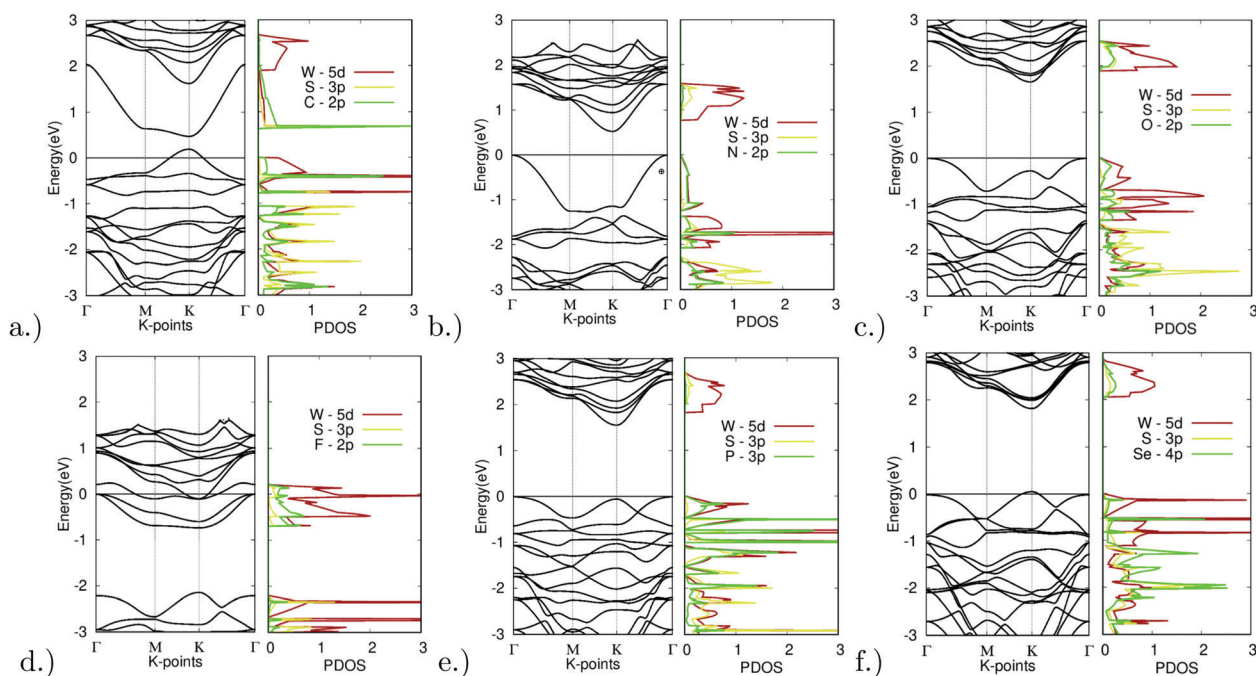


Fig. 8 Electronic structure of X site dopants. (left) Band structure of X site dopants. (right) Projected density of states of X site dopants.





Doping with C resulted in a direct bandgap of 0.28 eV at the *K* symmetry point. The lowest unoccupied band dips far below that of the other unoccupied bands. The C-2p orbital largely dominates the lowest point of this band. Extra holes moved up to higher energy levels, thus shrinking the bandgap. The top valence band was dominated by the C-2p and W-5d orbitals, a sign of hybridization. This indicates that an emerging bond between the W and C atoms is the main reason for the bandgap reduction. This can be further confirmed by the relatively short bond length absorbed, as seen in Table 2 mentioned earlier, with a bond length of 3.8437 bohr being the second shortest bond length observed out of all the X site dopants.

As another promising result, doping with nitrogen also showed ideal electronic properties. Fig. 8(b) depicts the band structure and projected density of states for N-doped WS<sub>2</sub>. Doping with C resulted in an indirect *K*- $\Gamma$  bandgap of 0.53 eV. The top valence band was dominated by the N-2p and W-5d orbitals, once again a sign of hybridization. This indicates that an emerging bond between the W and N atoms is the main reason for the bandgap reduction. This can be further confirmed by the relatively short bond length absorbed, as seen in Table 2 mentioned earlier, with a bond length of 3.8112 bohr being the shortest bond length observed out of all the X site dopants.

With successful yet small changes in the electronic structure, Fig. 8(c) depicts the band structure and projected density of states for O-doped WS<sub>2</sub>. Doping with O had only minor changes with a *K*- $\Gamma$  indirect bandgap of 1.66 eV. The W-5d orbital contributed the most to the CBM and VBM.

The only example of failed doping was seen for fluorine doping. Fig. 8(d) depicts the band structure and projected density of states for F-doped WS<sub>2</sub>. Doping with F appeared to be largely unsuccessful, resulting in degenerate doping and the formation of a metal. This was likely due to the high doping concentration. The density of states also shows missing states above 0 eV. This could be due to the extremely high electro-negativity that fluorine possesses.

Minor changes were once again observed in phosphorus doping. Fig. 8(e) depicts the band structure and projected density of states for P-doped WS<sub>2</sub>. Doping with P led to only minor changes with a *K*- $\Gamma$  indirect bandgap of 1.56 eV. The W-5d orbital contributed largely to the unoccupied bands, yet both the P-3p and W-5d orbitals contributed equally to the occupied bands.

Finally, Fig. 8(f) depicts the band structure and projected density of states for Se-doped WS<sub>2</sub>. Doping with Se led to only minor changes with a direct bandgap of 1.76 eV at the *K* symmetry point. The W-5d orbital contributed the most to the CBM and VBM.

Out of all materials tested for X site doping, only the C and N dopants fitted the bandgap threshold of being less than 0.92 eV. O, P, and Se all had successful yet minor bandgap changes. F resulted in degenerate doping.

### 3.3 Optical spectra

The optical spectra were then calculated for materials whose bandgap met the threshold requirement of a bandgap less than 0.92 eV. The bandgap, scissor operator, wavelength of peak

**Table 4** WS<sub>2</sub> Dopant bandgaps and optical properties. The bandgap in eV, scissor operator in eV, wavelength of peak absorption in nm, and absorption coefficient at the said peak in cm<sup>-1</sup> for all dopants are listed

Material	Bandgap (eV)	Scissor operator (eV)	$\lambda$ (nm)	$\alpha$ (cm <sup>-1</sup> )
Si	0.00			
Sc	0.10	0.18	1016	9119
Ti	0.06	0.05	1350	13 314
V	1.35			
Mn	0.00			
Zr	0.04	0.14	1347	18 830
Nb	1.71			
Mo	1.74			
Au	0.00			
C	0.28	-0.07	1000	8709
N	0.53	0.72	1000	870
O	1.66			
F	0.00			
P	1.56			
Se	1.76			

absorption coefficient within the NIR-II range, and absorption coefficient of the said peak, are listed. This is found in Table 4 with M site dopants on top and X site dopants at the bottom.

The optical spectra of the M site dopants which qualified for further calculations can be found in Fig. 9. It is apparent that all three materials – Ti, Zr, and Sc – had peaks at around 0.3–0.4 eV for the imaginary dielectric constant. Despite this similarity, they have very different absorption coefficients. Both Ti and Zr share similar shapes within the absorption graph with a gradual increase of the absorption coefficient after 900 nm. Overall, the absorption coefficient of Zr is higher than Ti. Sc appears to deviate from this trend with a much lower yet consistent absorption coefficient from 700–1700 nm. Sc had a maximum absorption coefficient of 9119 cm<sup>-1</sup> at a wavelength of 1016 nm. Ti had a maximum absorption coefficient of 13 314 cm<sup>-1</sup> at 1350 nm and Zr had a maximum absorption coefficient of 18 830 cm<sup>-1</sup> at a wavelength of 1347 nm.

The optical spectra of the X site dopants which qualified for further calculations can be found in Fig. 10. The optical spectra of C and N appear to be very different. There appear to be two peaks at 0.7 and 2.52 eV for C in the imaginary dielectric constant. There appear to be two peaks at 2.34 and 2.76 eV for N in the imaginary dielectric constant. Both materials show widely different shapes. Despite this, the absorption coefficient spectrum was rather plain. While C has a rather moderate absorption coefficient of around 7500–10 000 cm<sup>-1</sup>, N appears to be completely devoid of any strengths, despite having a rather promising bandgap.

It appears that the M site dopants had much higher absorption coefficients relative to the X site dopants. Among all materials that were tested, titanium and zirconium doped WS<sub>2</sub> had the highest absorption coefficients within the NIR-II range of 1000–1350 nm, offering to be potential NIR-II photothermal agents. The other materials seemed to offer only mediocre results.

### 3.4 Biocompatibility and cytotoxicity

A prerequisite for all biomedical materials is biocompatibility and cytotoxicity.<sup>62</sup> Despite existing biomedical applications





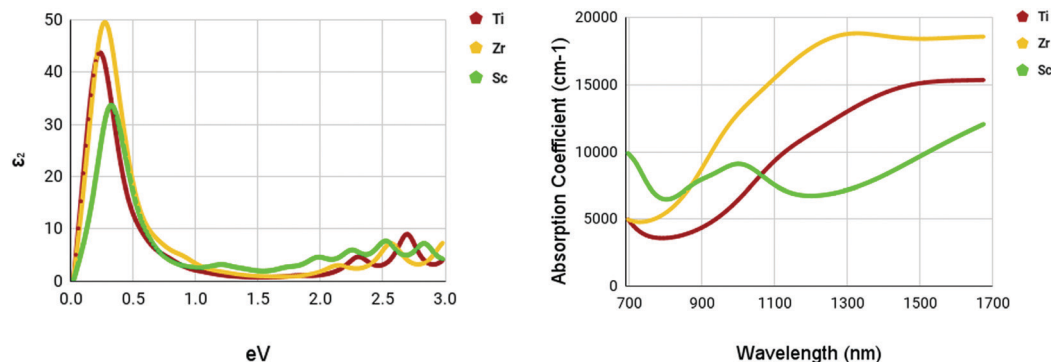


Fig. 9 Optical spectra of M site dopants. (left) Imaginary dielectric constant,  $\epsilon_2$  of M site dopants. (right) Absorption coefficient of M site dopants.

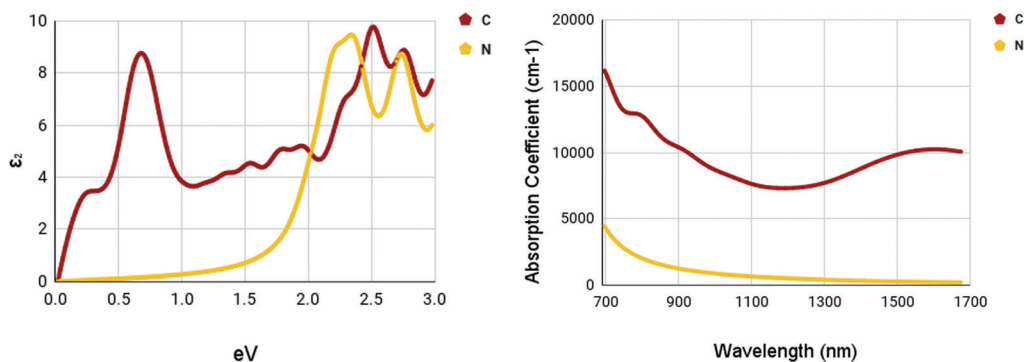


Fig. 10 Optical spectra of X site dopants. (left) Imaginary dielectric constant,  $\epsilon_2$  of X site dopants. (right) Absorption coefficient of X site dopants.

using TMDCs, few investigations into the biocompatibility and toxicity have been performed.<sup>63</sup> Nevertheless, there is still strong evidence for their safe usage. *In vivo* toxicology tests of fullerene-like  $\text{WS}_2$  nanoparticles on mammals showed no toxic effects.<sup>64</sup> Cytotoxicity tests of  $\text{WS}_2$  on human cell-lines, salivary gland cells, and A549 showed that they are nontoxic to cells and had a high cell viability after prolonged exposure.<sup>65,66</sup>

Additionally, because TMDCs have their chalcogens located on the exterior of the 2D layers, there are reduced interactions between cells and the interior metal which might have potentially caused damage to cells.<sup>67</sup> TMDCs that were composed of disulfides rather than diselenides or ditellurides were also found to be less hazardous.<sup>67</sup> Some TMDCs ( $\text{MoS}_2$ ,  $\text{WS}_2$ , and  $\text{WSe}_2$ ) have also been found to have greater cell viability than graphene materials.<sup>68,69</sup> Lastly, the cytotoxicity can be altered depending on the preparation method<sup>68</sup> or surface modifications (such as polyethylene glycol (PEG) or doxorubicin (DOX) coating).<sup>67,70</sup>

## 4 Conclusions

Numerous materials have been introduced into the testing of photothermal therapy, shedding light on the potential of this emerging cancer treatment. With monolayer tungsten disulfide

being the base of our nanomaterials, a range of dopant variations has been tested.

Out of the fifteen dopants tested for M site and X site doping, five dopants passed the bandgap threshold of less than 0.92 eV. The dopants, Ti, Zr, Sc, C, and N, had their optical spectra and constants calculated. The X site dopants appeared to be less prosperous. X site doping with N resulted in low absorption coefficients within the NIR-II range, with values less than  $1000 \text{ cm}^{-1}$ , proving to be a not ideal photoabsorber. X site doping with C proved to be better than N. The maximum absorption coefficient within the NIR-II range was  $8709 \text{ cm}^{-1}$  at a wavelength of 1000 nm.

M site doping was much more promising. Sc maintained an absorption coefficient of around  $6500\text{--}9500 \text{ cm}^{-1}$  in the NIR-II range with a peak at  $9119 \text{ cm}^{-1}$  at a wavelength of 1016 nm. Doping with Ti had higher absorption coefficients within the NIR-II range compared to Sc. The maximum absorption coefficient within the NIR-II range was  $13314 \text{ cm}^{-1}$  at a wavelength of 1350 nm. Zr was the most promising out of all three M site dopants. A slight peak was observed at around 1347 nm with an absorption coefficient of  $18830 \text{ cm}^{-1}$ .

Through Density Functional Theory calculations within the Abinit computational program suite, it was found that zirconium-doped and titanium-doped monolayer tungsten disulfide could be possible ablation agents for photothermal therapy in the second near-infrared window. With peak



absorption coefficients of 18 830 and 13 314  $\text{cm}^{-1}$  in the NIR-II range for zirconium-doped and titanium-doped, respectively, they show promise as photoabsorbers. Their absorption coefficients are competitive with other current photothermal therapy materials, but specialize in the NIR-II range, a more effective and efficient form of photothermal therapy. This makes these novel materials valuable and worth carrying out more in-depth studies. Further research should be done before these materials can reach clinical use. Future work includes an analysis of the photothermal conversion efficiency and the cytotoxicity of these materials. Additional research into different concentrations and dopants is also a potential avenue of research. This study provides a valuable guideline and lays the groundwork for future fabrication and experimentation on tungsten disulfide and its dopant variants for photothermal therapy.

## Data availability

The raw data required to reproduce these findings cannot be shared at this time due to technical or time limitations. The processed data required to reproduce these findings cannot be shared at this time due to technical or time limitations.

## Author contributions

All of the authors made important contributions to this work. Specifically, Athan Zhang conceived and designed the research procedures, carried out DFT calculations, executed data visualization, contributed to writing – original draft, and contributed to writing – review and editing. Xuan Luo aided in designing the methodology and contributed to writing – review and editing.

## Conflicts of interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

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